

isc N-Channel MOSFET Transistor

2SK1635

DESCRIPTION

- Drain Current –I_D= 50A@ T_C=25 °C
- Drain Source Voltage-
- : V_{DSS}=60V(Min)
- Minimum Lot-to-Lot variations for robust device performance and reliable operation

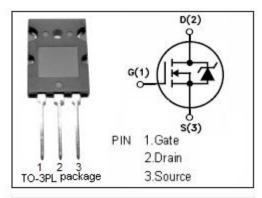


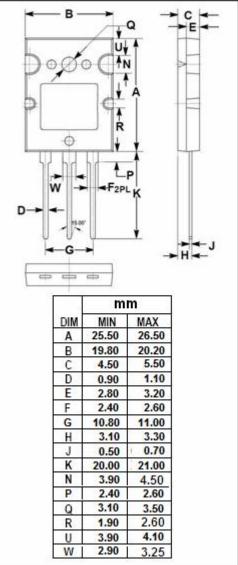
APPLICATIONS

- · High current,
- low voltage



SYMBOL	ARAMETER	VALUE	UNIT
V _{DSS}	Drain-Source Voltage (V _{GS} =0)	60	V
V _{GS}	Gate-Source Voltage	±30	V
ID	Drain Current-continuous@ TC=25℃	50	Α
P _{tot}	Total Dissipation@TC=25℃	130	W
T _j	Max. Operating Junction Temperature	150	$^{\circ}$
T _{stg}	Storage Temperature Range	-55~150	$^{\circ}$







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• ELECTRICAL CHARACTERISTICS (Tc=25°C)

SYMBOL	PARAMETER	CONDITIONS	MIN	TYP	MAX	UNIT
$V_{(BR)DSS}$	Drain-Source Breakdown Voltage	V _{GS} =0; I _D = 10mA	60			V
V _{GS(th)}	Gate Threshold Voltage	V _{DS} =10 V _{GS} ; I _D =1mA	1.0		5.0	V
R _{DS(on)}	Drain-Source On-stage Resistance	V _{GS} =10V; I _D =25A			0.03	Ω
I _{GSS}	Gate Source Leakage Current	V _{GS} = ±30V;V _{DS} = 0			±100	nA
I _{DSS}	Zero Gate Voltage Drain Current	V _{DS} =60V; V _{GS} = 0			500	uA



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